# SKR 20F



## **Fast Recovery Rectifier** Diode

#### SKR 20F

### **Features**

- CAL-Diode (controlled axial lifetime technology), patent no. DE 431044
- Very short recovery timeSoft recovery under all conditions
- Up to 1200 V reverse voltage
- Epoxy meets UL 94V-0 flammability classification

### **Typical Applications**

- Inverse diode for power transistors
- Inverter
- Power supply
- Snubber and clamping diode

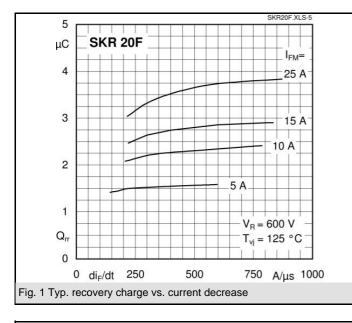
V <sub>RSM</sub>	V <sub>RRM</sub>	I <sub>FRMS</sub> = 30 A (maximum value for continuous operation)		
V	V	I <sub>FAV</sub> = 20 A (sin. 180; 50 Hz; T <sub>c</sub> = 85 °C)		
1000	1000	SKR 20F10		
1200	1200	SKR 20F12		

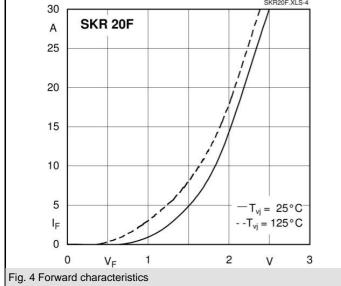
Symbol	Conditions	Values	Units
I <sub>FAV</sub>	sin. 180; T <sub>c</sub> = 85 (100) °C	20 (17)	А
I <sub>FSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	150	A
	T <sub>vi</sub> = 150 °C; 10 ms	140	А
i²t	T <sub>vj</sub> = 25 °C; 8,3 10 ms	110	A²s
	T <sub>vj</sub> = 150 °C; 8,3 10 ms	100	A²s
V <sub>F</sub>	T <sub>vi</sub> = 25 °C; I <sub>F</sub> = 15 A	max. 2,5	V
V <sub>(TO)</sub>	T <sub>vi</sub> = 150 °C	max. 1,2	V
r <sub>T</sub>	T <sub>vi</sub> = 150 °C	max. 70	mΩ
I <sub>RD</sub>	$T_{vj}^{3}$ = 25 °C; $V_{RD}$ = $V_{RRM}$	max. 0,1	mA
I <sub>RD</sub>	T <sub>vj</sub> = 125 °C; V <sub>RD</sub> = V <sub>RRM</sub>	max. 2	mA
Q <sub>rr</sub>	T <sub>vj</sub> = 125 °C, I <sub>F</sub> = 15 A,	2,7	μC
I <sub>RM</sub>	-di/dt = 400 A/µs, V <sub>R</sub> = 600 V	16	А
t <sub>rr</sub>		380	ns
E <sub>rr</sub>		-	mJ
R <sub>th(j-c)</sub>		0,7	K/W
R <sub>th(c-s)</sub>		0,3	K/W
T <sub>vj</sub> `´		- 40 150	°C
T <sub>stg</sub>		- 40 150	°C
V <sub>isol</sub>		-	٧~
M <sub>s</sub>	to heatsink	0,55 0,8	Nm
а			m/s²
m	approx.	2	g
Case		E 39	

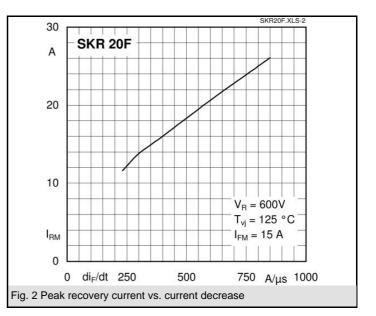


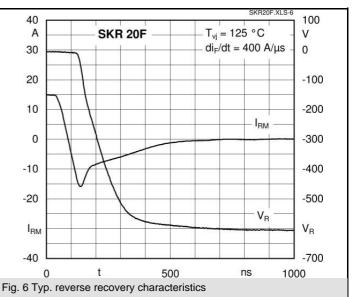
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#### DDE, I H Y RISTOR, MOI

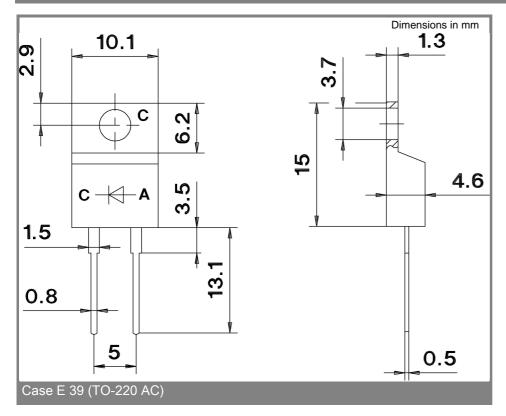








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